

N-channel 40 V, 13.6 mOhm, logic level MOSFET in LFPAK56D using NextPowerS3 technology 26 September 2022 Produc

Product data sheet

1. General description

Dual logic level N-channel MOSFET in an LFPAK56D (Dual Power-SO8) package using NextPowerS3 technology.

2. Features and benefits

- Dual MOSFET
- Repetitive avalanche rated
- High reliability LFPAK56D package
- Copper-clip, solder die attach
- Qualified to 175 °C

3. Applications

- Brushless DC motor control
- DC-to-DC converters
- High-performance synchronous rectification
- · High performance and high efficiency server power supply

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	40	V
ID	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	42	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	46	W
Tj	junction temperature			-55	-	175	°C
Static chara	acteristics FET1 and FET2						
R _{DSon}	drain-source on-state	V _{GS} = 10 V; I _D = 10 A; T _j = 25 °C		7.9	11.4	13.6	mΩ
	resistance	V _{GS} = 10 V; I _D = 10 A; T _j = 105 °C		10.9	16	20.4	mΩ
Dynamic ch	naracteristics FET1 and FE	T2					
Q _{GD}	gate-drain charge	I_D = 10 A; V _{DS} = 32 V; V _{GS} = 5 V; T _j = 25 °C		-	1.8	4.2	nC
Q _{G(tot)}	total gate charge	I_D = 10 A; V _{DS} = 32 V; V _{GS} = 10 V; T _j = 25 °C		-	13	19.4	nC
Avalanche	Ruggedness FET1 and FE	Γ2	-	_			
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$ I_D = 39.9 \text{ A}; V_{sup} \le 40 \text{ V}; \text{ R}_{GS} = 50 \Omega; \\ V_{GS} = 10 \text{ V}; \text{ T}_{j(init)} = 25 \text{ °C}; \text{ Fig. 4} $	[2] [3]	-	-	10.6	mJ

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N-channel 40 V, 13.6 mOhm, logic level MOSFET in LFPAK56D using NextPowerS3 technology

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Source-drain d	iode FET1 and FET2						
Qr	recovered charge	$\label{eq:IS} \begin{array}{l} I_{S} = 10 \; A; \; dI_{S}/dt = -100 \; A/\mu s; \; V_{GS} = 0 \; V; \\ V_{DS} = 20 \; V; \; T_{j} = 25 \; ^{\circ} C \end{array}$	[4]	-	16.2	-	nC

[1] 42A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[3] Refer to application note AN10273 for further information.

[4] Includes capacitive recovery

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source1	8 7 6 5	
2	G1	gate1		D1 D1 D2 D2
3	S2	source2		
4	G2	gate2		
5	D2	drain2		
6	D2	drain2		
7	D1	drain1		S1 G1 S2 G2
8	B D1 drain1	drain1	LFPAK56D; Dual LFPAK (SOT1205)	mbk725

6. Ordering information

Table 3. Ordering information

Type number Package					
	Name	Description	Version		
PSMN014-40HLD		plastic, single ended surface mounted package (LFPAK56D); 8 leads	SOT1205		

7. Marking

Table 4. Marking codes	
Type number	Marking code
PSMN014-40HLD	14DS40H

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	40	V
V _{GS}	gate-source voltage	DC; T _j = 25 °C	-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	46	W

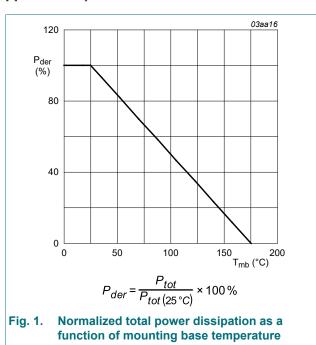
Symbol	Parameter	Conditions		Min	Max	Unit
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	42	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	30	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3		-	169	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
Source-drain d	iode FET1 and FET2					
I _S	source current	T _{mb} = 25 °C		-	42	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	169	А
Avalanche Rug	gedness FET1 and FET2				·	
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 39.9 A; $V_{sup} \le 40$ V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; <u>Fig. 4</u>	[2] [3]	-	10.6	mJ
I _{AS}	non-repetitive avalanche current	V_{sup} = 40 V; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; R _{GS} = 50 Ω; <u>Fig. 4</u>	[4]	-	39.9	A

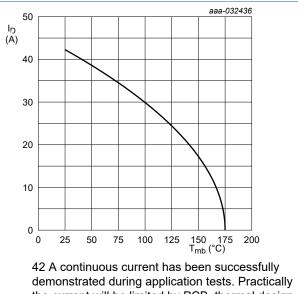
[1] 42A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[3] Refer to application note AN10273 for further information.

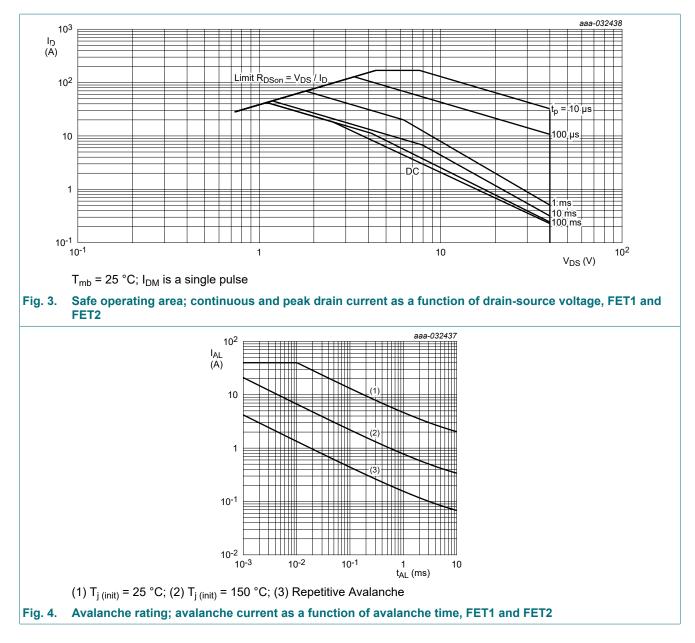
[4] Protected by 100% test





demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature. $V_{GS} \ge 10 \text{ V}$

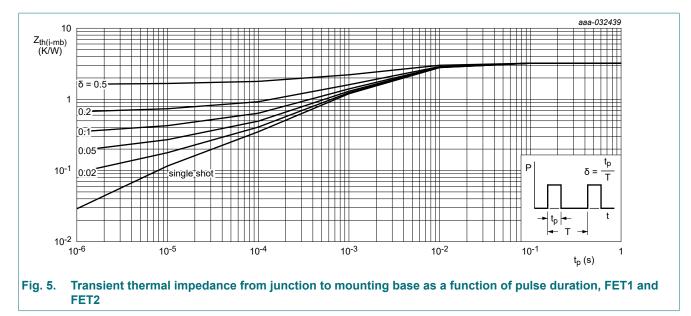
Fig. 2. Continuous drain current as a function of mounting base temperature, FET1 and FET2



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	3	3.23	K/W

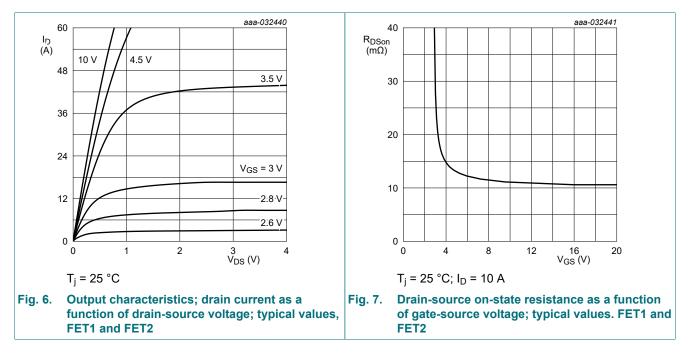


10. Characteristics

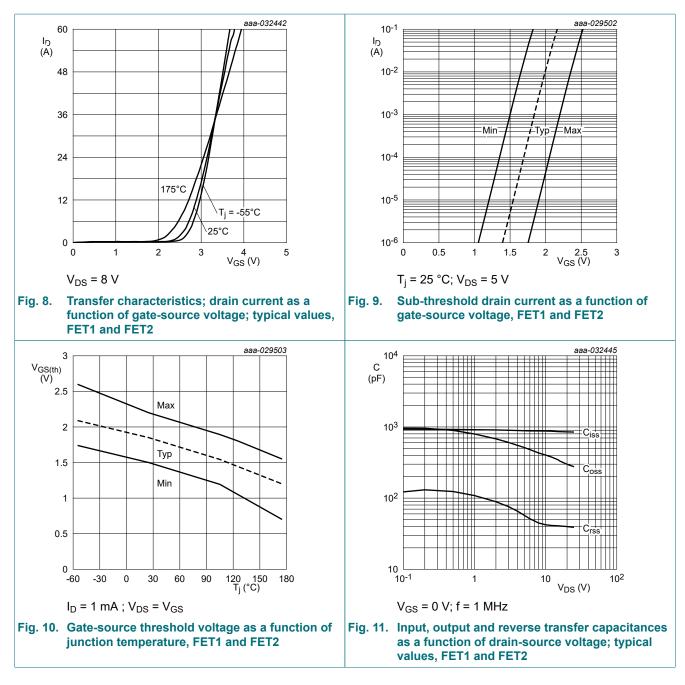
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics FET1 and FET2	· · ·	I			
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	40	43	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -40 °C	-	40.5	-	V
		I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	36	40	-	V
V _{GS(th)}	gate-source threshold voltage	I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 25 °C; <u>Fig. 9;</u> <u>Fig. 10</u>	1.5	1.85	2.2	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 175 °C; Fig. 10	0.7	-	-	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = -55 °C; <u>Fig. 10</u>	-	-	2.6	V
I _{DSS}	drain leakage current	V _{DS} = 40 V; V _{GS} = 0 V; T _j = 25 °C	-	0.01	5	μA
		V _{DS} = 16 V; V _{GS} = 0 V; T _j = 125 °C	-	0.14	10	μA
		V _{DS} = 40 V; V _{GS} = 0 V; T _j = 175 °C	-	26	500	μA
I _{GSS}	gate leakage current	V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
		V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state	V _{GS} = 10 V; I _D = 10 A; T _j = 25 °C	7.9	11.4	13.6	mΩ
	resistance	V _{GS} = 10 V; I _D = 10 A; T _j = 105 °C	10.9	16	20.4	mΩ
		V _{GS} = 10 V; I _D = 10 A; T _j = 125 °C	12	17.4	21.9	mΩ
		V _{GS} = 10 V; I _D = 10 A; T _j = 175 °C	14.5	20.9	26.4	mΩ
		V _{GS} = 4.5 V; I _D = 10 A; T _j = 25 °C	9.8	14.1	16.9	mΩ
		V _{GS} = 4.5 V; I _D = 10 A; T _j = 105 °C	13.5	20	25.4	mΩ
		V _{GS} = 4.5 V; I _D = 10 A; T _j = 125 °C	14.8	21.6	27.2	mΩ
		V _{GS} = 4.5 V; I _D = 10 A; T _j = 175 °C	18	26.6	32.8	mΩ
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	0.7	1.8	4.2	Ω

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Dynamic ch	naracteristics FET1 and FE	T2					
Q _{G(tot)}	total gate charge	I_D = 10 A; V_{DS} = 32 V; V_{GS} = 10 V; T _j = 25 °C		-	13	19.4	nC
		I _D = 10 A; V _{DS} = 32 V; V _{GS} = 5 V;		-	6.8	10.2	nC
Q _{GS}	gate-source charge	T _j = 25 °C		-	2.3	3.8	nC
Q _{GD}	gate-drain charge			-	1.8	4.2	nC
C _{iss}	input capacitance	V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz; T _j = 25 °C; <u>Fig. 11</u>		-	848	1160	pF
C _{oss}	output capacitance			-	280	420	pF
C _{rss}	reverse transfer capacitance			-	39	84	pF
t _{d(on)}	turn-on delay time	V_{DS} = 32 V; R _L = 3.2 Ω; V _{GS} = 5 V;		-	6.5	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$		-	9.7	-	ns
t _{d(off)}	turn-off delay time	_		-	10.1	-	ns
t _f	fall time	-		-	7.8	-	ns
Source-dra	in diode FET1 and FET2	1					
V _{SD}	source-drain voltage	I_{S} = 10 A; V_{GS} = 0 V; T_{j} = 25 °C; <u>Fig. 12</u>		-	0.81	1	V
t _{rr}	reverse recovery time	I _S = 10 A; dI _S /dt = -100 A/µs; V _{GS} = 0 V;		-	21.5	-	ns
Q _r	recovered charge		[1]	-	16.2	-	nC

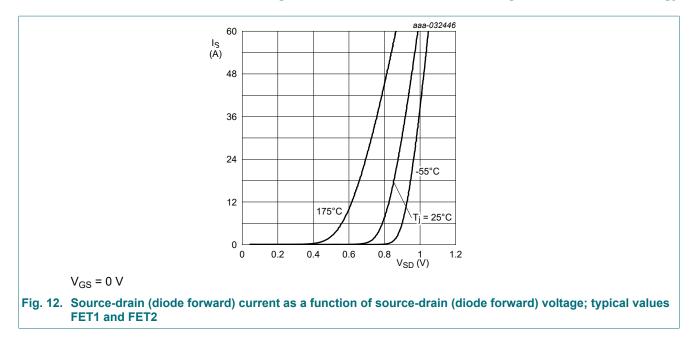
[1] Includes capacitive recovery



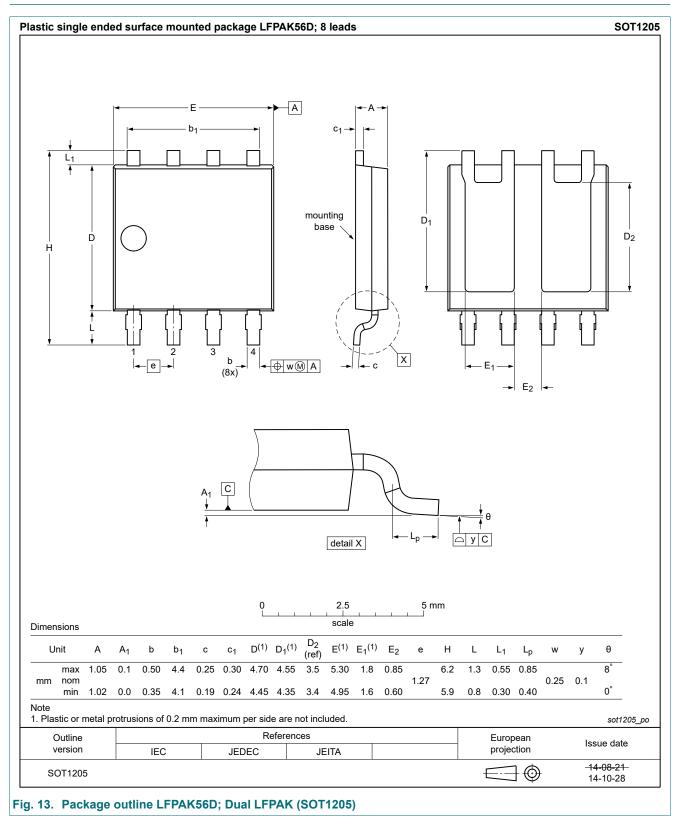
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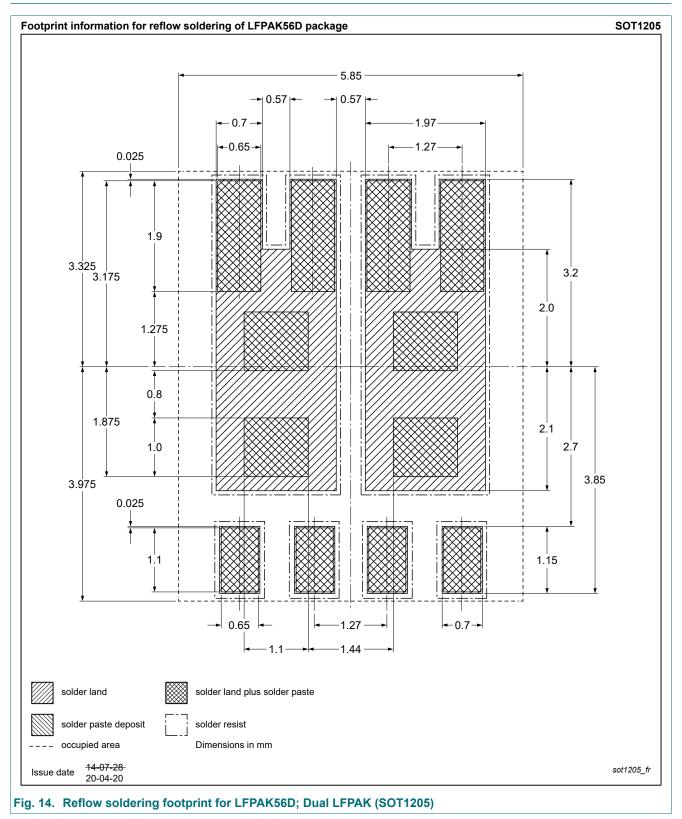
N-channel 40 V, 13.6 mOhm, logic level MOSFET in LFPAK56D using NextPowerS3 technology



11. Package outline



12. Soldering



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13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product data sheet

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